

CD4008BMS

CMOS 4-Bit Full Adder With Parallel Carry Out

November 1994

Features

- High-Voltage Type (20V Rating)
- 4 Sum Outputs Plus Parallel Look-ahead Carry-Output
- High-Speed Operation - Sum In-To-Sum Out, 160ns Typ; Carry In-To-Carry Out, 5ns Typ. At VDD = 10V, CL=50pF
- Standardized Symmetrical Output Characteristics
- 100% Tested For Quiescent Current At 20V
- Maximum Input Current of 1 μ A at 18V Over Full Package-Temperature Range;
 - 100nA at 18V and 25°C
- Noise Margin (Over Full Package Temperature Range):
 - 1V at VDD = 5V
 - 2V at VDD = 10V
 - 2.5V at VDD = 15V
- 5V, 10V and 15V Parametric Ratings
- Meets All Requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications

- Binary Addition/Arithmetic Units

Description

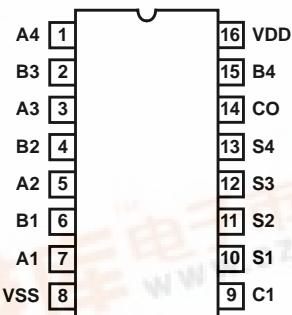
CD4008BMS types consist of four full adder stages with fast look ahead carry provision from stage to stage. Circuitry is included to provide a fast "parallel-carry-out" but to permit high-speed operation in arithmetic sections using several CD4008BMS's.

CD4008BMS inputs include the four sets of bits to be added, A1 to A4 and B1 to B4, in addition to the "Carry In" bit from a previous section. CD4008BMS outputs include the four sum bits, S1 to S4. In addition to the high speed "parallel-carry-out" which may be utilized at a succeeding CD4008BMS section.

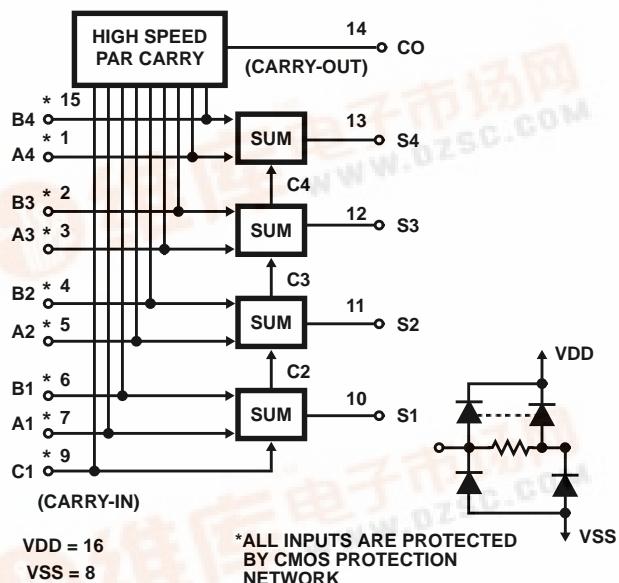
The CD4008BMS is supplied in these 16-lead outline packages:

Braze Seal DIP H4T
 Frit Seal DIP H1F
 Ceramic Flatpack H6W

Pinout

CD4008BMS
TOP VIEW

Logic Diagram



TRUTH TABLE

A _i	B _i	C _i	C _O	SUM
0	0	0	0	0
1	0	0	0	1
0	1	0	0	1
1	1	0	1	0
0	0	1	0	1
1	0	1	1	0
0	1	1	1	0
1	1	1	1	1

Specifications CD4008BMS

Absolute Maximum Ratings				Reliability Information						
DC Supply Voltage Range, (VDD)	-0.5V to +20V (Voltage Referenced to VSS Terminals)			Thermal Resistance	θ_{ja}	θ_{jc}				
Input Voltage Range, All Inputs	-0.5V to VDD +0.5V			Ceramic DIP and FRIT Package	80°C/W	20°C/W				
DC Input Current, Any One Input	$\pm 10\text{mA}$			Flatpack Package	70°C/W	20°C/W				
Operating Temperature Range	-55°C to +125°C Package Types D, F, K, H			Maximum Package Power Dissipation (PD) at +125°C For TA = -55°C to +100°C (Package Type D, F, K)	500mW					
Storage Temperature Range (TSTG)	-65°C to +150°C			For TA = +100°C to +125°C (Package Type D, F, K)	Derate Linearity at 12mW/°C to 200mW					
Lead Temperature (During Soldering)	+265°C At Distance 1/16 ± 1/32 Inch (1.59mm ± 0.79mm) from case for 10s Maximum			Device Dissipation per Output Transistor	100mW					
				For TA = Full Package Temperature Range (All Package Types)						
				Junction Temperature	+175°C					
TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS										
PARAMETER	SYMBOL	CONDITIONS (NOTE 1)		GROUP A SUBGROUPS	TEMPERATURE	LIMITS		UNITS		
						MIN	MAX			
Supply Current	IDD	VDD = 20V, VIN = VDD or GND		1	+25°C	-	10	µA		
				2	+125°C	-	1000	µA		
		VDD = 18V, VIN = VDD or GND		3	-55°C	-	10	µA		
Input Leakage Current	IIL	VIN = VDD or GND	VDD = 20	1	+25°C	-100	-	nA		
			VDD = 20	2	+125°C	-1000	-	nA		
		VDD = 18V		3	-55°C	-100	-	nA		
Input Leakage Current	IIH	VIN = VDD or GND	VDD = 20	1	+25°C	-	100	nA		
			VDD = 20	2	+125°C	-	1000	nA		
		VDD = 18V		3	-55°C	-	100	nA		
Output Voltage	VOL15	VDD = 15V, No Load		1, 3	+25°C, +125°C, -55°C	-	50	mV		
Output Voltage	VOH15	VDD = 15V, No Load (Note 3)		1, 3	+25°C, +125°C, -55°C	14.95	-	V		
Output Current (Sink)	IOL5	VDD = 5V, VOUT = 0.4V		1	+25°C	0.53	-	mA		
Output Current (Sink)	IOL10	VDD = 10V, VOUT = 0.5V		1	+25°C	1.4	-	mA		
Output Current (Sink)	IOL15	VDD = 15V, VOUT = 1.5V		1	+25°C	3.5	-	mA		
Output Current (Source)	IOH5A	VDD = 5V, VOUT = 4.6V		1	+25°C	-	-0.53	mA		
Output Current (Source)	IOH5B	VDD = 5V, VOUT = 2.5V		1	+25°C	-	-1.8	mA		
Output Current (Source)	IOH10	VDD = 10V, VOUT = 9.5V		1	+25°C	-	-1.4	mA		
Output Current (Source)	IOH15	VDD = 15V, VOUT = 13.5V		1	+25°C	-	-3.5	mA		
N Threshold Voltage	VNTH	VDD = 10V, ISS = -10µA		1	+25°C	-2.8	-0.7	V		
P Threshold Voltage	VPTH	VSS = 0V, IDD = 10µA		1	+25°C	0.7	2.8	V		
Functional	F	VDD = 2.8V, VIN = VDD or GND		7	+25°C	VOH > VDD/2	VOL < VDD/2	V		
		VDD = 20V, VIN = VDD or GND		7	+25°C					
		VDD = 18V, VIN = VDD or GND		8A	+125°C					
		VDD = 3V, VIN = VDD or GND		8B	-55°C					
Input Voltage Low (Note 2)	VIL	VDD = 5V, VOH > 4.5V, VOL < 0.5V		1, 2, 3	+25°C, +125°C, -55°C	-	1.5	V		
Input Voltage High (Note 2)	VIH	VDD = 5V, VOH > 4.5V, VOL < 0.5V		1, 2, 3	+25°C, +125°C, -55°C	3.5	-	V		
Input Voltage Low (Note 2)	VIL	VDD = 15V, VOH > 13.5V, VOL < 1.5V		1, 2, 3	+25°C, +125°C, -55°C	-	4	V		
Input Voltage High (Note 2)	VIH	VDD = 15V, VOH > 13.5V, VOL < 1.5V		1, 2, 3	+25°C, +125°C, -55°C	11	-	V		
NOTES: 1. All voltages referenced to device GND, 100% testing being implemented.				3. For accuracy, voltage is measured differentially to VDD. Limit is 0.050V max.						
2. Go/No Go test with limits applied to inputs										

Specifications CD4008BMS

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS (NOTE 1, 2)	GROUP A SUBGROUPS	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Propagation Delay Sum In to Sum Out	TPHL1 TPLH1	VDD = 5V, VIN = VDD or GND	9	+25°C	-	800	ns
			10, 11	+125°C, -55°C	-	1080	ns
Propagation Delay Carry In To Cum Out	TPHL2 TPLH2	VDD = 5V, VIN = VDD or GND	9	+25°C	-	740	ns
			10, 11	+125°C, -55°C	-	999	ns
Propagation Delay Sum In To Carry Out	TPHL3 TPLH3	VDD = 5V, VIN = VDD or GND	9	+25°C	-	400	ns
			10, 11	+125°C, -55°C	-	540	ns
Propagation Delay Carry In To Carry Out	TPHL4 TPLH4	VDD = 5V, VIN = VDD or GND	9	+25°C	-	200	ns
			10, 11	+125°C, -55°C	-	270	ns
Transition Time	TTHL TTLH	VDD = 5V, VIN = VDD or GND	9	+25°C	-	200	ns
			10, 11	+125°C, -55°C	-	270	ns

NOTES:

1. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
2. -55°C and +125°C limits guaranteed, 100% testing being implemented.

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Supply Current	IDD	VDD = 5V, VIN = VDD or GND	1, 2	-55°C, +25°C	-	5	µA
				+125°C	-	150	µA
		VDD = 10V, VIN = VDD or GND	1, 2	-55°C, +25°C	-	10	µA
				+125°C	-	300	µA
		VDD = 15V, VIN = VDD or GND	1, 2	-55°C, +25°C	-	10	µA
				+125°C	-	600	µA
Output Voltage	VOL	VDD = 5V, No Load	1, 2	+25°C, +125°C, -55°C	-	50	mV
Output Voltage	VOL	VDD = 10V, No Load	1, 2	+25°C, +125°C, -55°C	-	50	mV
Output Voltage	VOH	VDD = 5V, No Load	1, 2	+25°C, +125°C, -55°C	4.95	-	V
Output Voltage	VOH	VDD = 10V, No Load	1, 2	+25°C, +125°C, -55°C	9.95	-	V
Output Current (Sink)	IOL5	VDD = 5V, VOUT = 0.4V	1, 2	+125°C	0.36	-	mA
Output Current (Sink)	IOL5	VDD = 5V, VOUT = 0.4V		-55°C	0.64	-	mA
Output Current (Sink)	IOL10	VDD = 10V, VOUT = 0.5V	1, 2	+125°C	0.9	-	mA
Output Current (Sink)	IOL10	VDD = 10V, VOUT = 0.5V		-55°C	1.6	-	mA
Output Current (Sink)	IOL15	VDD = 15V, VOUT = 1.5V	1, 2	+125°C	2.4	-	mA
Output Current (Sink)	IOL15	VDD = 15V, VOUT = 1.5V		-55°C	4.2	-	mA
Output Current (Source)	IOH5A	VDD = 5V, VOUT = 4.6V	1, 2	+125°C	-	-0.36	mA
Output Current (Source)	IOH5A	VDD = 5V, VOUT = 4.6V		-55°C	-	-0.64	mA
Output Current (Source)	IOH5B	VDD = 5V, VOUT = 2.5V	1, 2	+125°C	-	-1.15	mA
Output Current (Source)	IOH5B	VDD = 5V, VOUT = 2.5V		-55°C	-	-2.0	mA

Specifications CD4008BMS

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

PARAMETER	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Output Current (Source)	IOH10	VDD = 10V, VOUT = 9.5V	1, 2	+125°C	-	-0.9	mA
				-55°C	-	-1.6	mA
Output Current (Source)	IOH15	VDD = 15V, VOUT = 13.5V	1, 2	+125°C	-	-2.4	mA
				-55°C	-	-4.2	mA
Input Voltage Low	VIL	VDD = 10V, VOH > 9V, VOL < 1V	1, 2	+25°C, +125°C, -55°C	-	3	V
Input Voltage High	VIH	VDD = 10V, VOH > 9V, VOL < 1V	1, 2	+25°C, +125°C, -55°C	+7	-	V
Propagation Delay Sum In To Sum Out	TPHL1 TPLH1	VDD = 10V	1, 2, 3	+25°C	-	320	ns
		VDD = 15V	1, 2, 3	+25°C	-	230	ns
Propagation Delay Carry In To Sum Out	TPHL2 TPLH2	VDD = 10V	1, 2, 3	+25°C	-	310	ns
		VDD = 15V	1, 2, 3	+25°C	-	230	ns
Propagation Delay Sum In To Carry Out	TPLH3 TPHL3	VDD = 10V	1, 2, 3	+25°C	-	180	ns
		VDD = 15V	1, 2, 3	+25°C	-	130	ns
Propagation Delay Carry In To Carry Out	TPHL4 TPLH4	VDD = 10V	1, 2, 3	+25°C	-	100	ns
		VDD = 15V	1, 2, 3	+25°C	-	80	ns
Transition Time	TTHL TTLH	VDD = 10V	1, 2, 3	+25°C	-	100	ns
		VDD = 15V	1, 2, 3	+25°C	-	80	ns
Input Capacitance	CIN	Any Input	1, 2	+25°C	-	7.5	pF

NOTES:

1. All voltages referenced to device GND.
2. The parameters listed on Table 3 are controlled via design or process and are not directly tested. These parameters are characterized on initial design release and upon design changes which would affect these characteristics.
3. CL = 50pF, RL = 200K, Input TR, TF < 20ns.

TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Supply Current	IDD	VDD = 20V, VIN = VDD or GND	1, 4	+25°C	-	25	µA
N Threshold Voltage	VNTH	VDD = 10V, ISS = -10µA	1, 4	+25°C	-2.8	-0.2	V
N Threshold Voltage Delta	ΔVNTH	VDD = 10V, ISS = -10µA	1, 4	+25°C	-	±1	V
P Threshold Voltage	VPTH	VSS = 0V, IDD = 10µA	1, 4	+25°C	0.2	2.8	V
P Threshold Voltage Delta	ΔVPTH	VSS = 0V, IDD = 10µA	1, 4	+25°C	-	±1	V
Functional	F	VDD = 18V, VIN = VDD or GND	1	+25°C	VOH > VDD/2	VOL < VDD/2	V
		VDD = 3V, VIN = VDD or GND					

Specifications CD4008BMS

TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS

PARAMETER	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		UNITS
					MIN	MAX	
Propagation Delay Time	TPHL TPLH	VDD = 5V	1, 2, 3, 4	+25°C	-	1.35 x +25°C Limit	ns

NOTES: 1. All voltages referenced to device GND.
 2. CL = 50pF, RL = 200K, Input TR, TF < 20ns.

3. See Table 2 for +25°C limit.
 4. Read and Record

TABLE 5. BURN-IN AND LIFE TEST DELTA PARAMETERS +25°C

PARAMETER	SYMBOL	DELTA LIMIT
Supply Current - MSI-2	IDD	± 1.0µA
Output Current (Sink)	IOL5	± 20% x Pre-Test Reading
Output Current (Source)	IOH5A	± 20% x Pre-Test Reading

TABLE 6. APPLICABLE SUBGROUPS

CONFORMANCE GROUP	MIL-STD-883 METHOD	GROUP A SUBGROUPS	READ AND RECORD
Initial Test (Pre Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A
Interim Test 1 (Post Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A
Interim Test 2 (Post Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A
PDA (Note 1)	100% 5004	1, 7, 9, Deltas	
Interim Test 3 (Post Burn-In)	100% 5004	1, 7, 9	IDD, IOL5, IOH5A
PDA (Note 1)	100% 5004	1, 7, 9, Deltas	
Final Test	100% 5004	2, 3, 8A, 8B, 10, 11	
Group A	Sample 5005	1, 2, 3, 7, 8A, 8B, 9, 10, 11	
Group B	Subgroup B-5	Sample 5005	1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas
	Subgroup B-6	Sample 5005	1, 7, 9
Group D	Sample 5005	1, 2, 3, 8A, 8B, 9	Subgroups 1, 2 3

NOTE: 1. 5% Parameteric, 3% Functional; Cumulative for Static 1 and 2.

TABLE 7. TOTAL DOSE IRRADIATION

CONFORMANCE GROUPS	MIL-STD-883 METHOD	TEST		READ AND RECORD	
		PRE-IRRAD	POST-IRRAD	PRE-IRRAD	POST-IRRAD
Group E Subgroup 2	5005	1, 7, 9	Table 4	1, 9	Table 4

TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS

FUNCTION	OPEN	GROUND	VDD	9V ± 0.5V	OSCILLATOR	
					50kHz	25kHz
Static Burn-In 1 Note 1	10 - 14	1 - 9, 15	16			
Static Burn-In 2 Note 1	10 - 14	8	1 - 7, 9, 15, 16			
Dynamic Burn-In Note 1	-	8	16	10 - 14	2, 4, 6, 15	1, 3, 5, 7, 9
Irradiation Note 2	10 - 14	8	1 - 7, 9, 15, 16			

Specifications CD4008BMS

TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS

FUNCTION	OPEN	GROUND	VDD	9V ± -0.5V	OSCILLATOR	
					50kHz	25kHz

NOTE:

1. Each pin except VDD and GND will have a series resistor of $10K \pm 5\%$, $VDD = 18V \pm 0.5V$
2. Each pin except VDD and GND will have a series resistor of $47K \pm 5\%$; Group E, Subgroup 2, sample size is 4 dice/wafer, 0 failures, $VDD = 10V \pm 0.5V$

Typical Propagation Delay

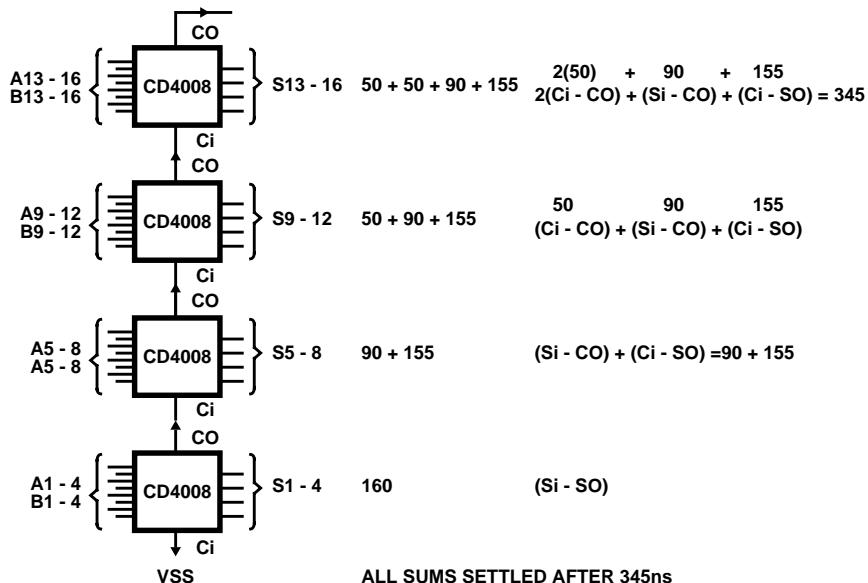


FIGURE 1. PROPAGATION DELAY FOR A 16 BIT ADDER (10V OPERATION)

All Intersil semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see web site <http://www.intersil.com>

Sales Office Headquarters

NORTH AMERICA

Intersil Corporation
P. O. Box 883, Mail Stop 53-204
Melbourne, FL 32902
TEL: (321) 724-7000
FAX: (321) 724-7240

EUROPE

Intersil SA
Mercure Center
100, Rue de la Fusée
1130 Brussels, Belgium
TEL: (32) 2.724.2111
FAX: (32) 2.724.22.05

ASIA

Intersil (Taiwan) Ltd.
Taiwan Limited
7F-6, No. 101 Fu Hsing North Road
Taipei, Taiwan
Republic of China
TEL: (886) 2 2716 9310
FAX: (886) 2 2715 3029

CD4008BMS

Typical Performance Characteristics

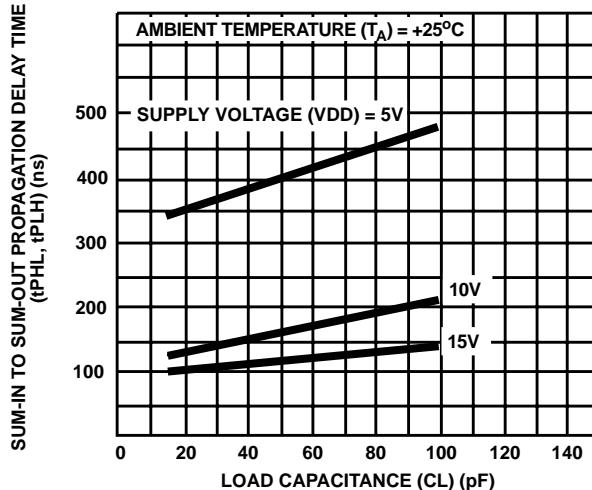


FIGURE 2. TYPICAL SUM-IN TO SUM-OUT PROPAGATION DELAY TIME vs LOAD CAPACITANCE

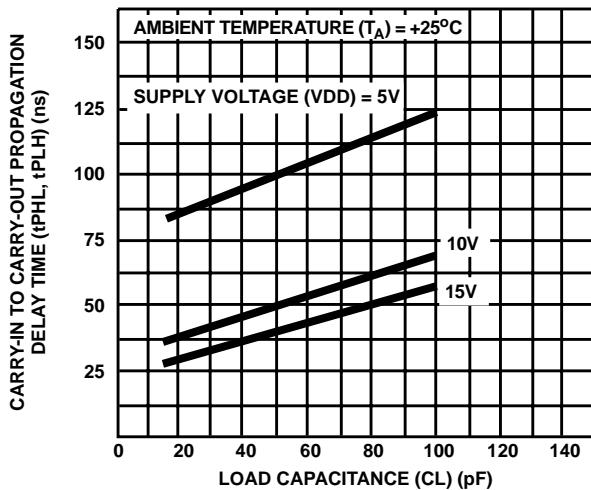


FIGURE 3. TYPICAL CARRY-IN TO CARRY-OUT PROPAGATION DELAY TIME vs LOAD CAPACITANCE

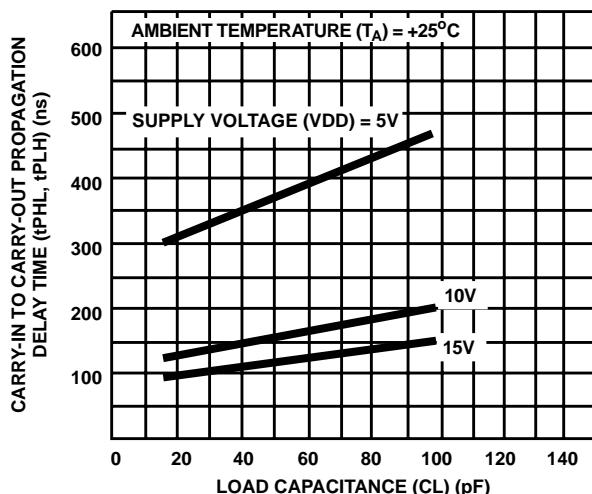


FIGURE 4. TYPICAL CARRY-IN TO SUM-OUT PROPAGATION DELAY TIME vs LOAD CAPACITANCE

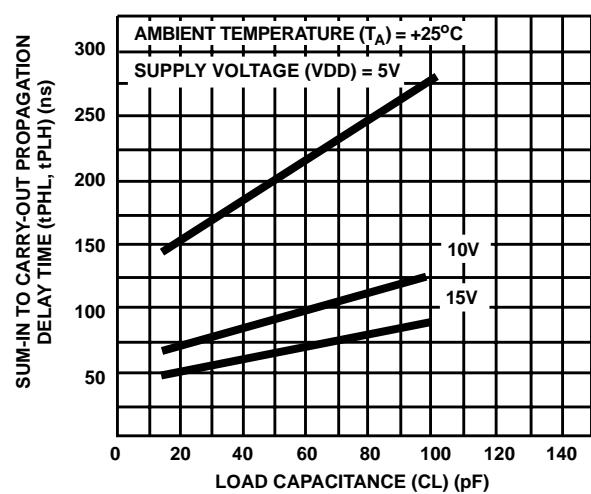


FIGURE 5. TYPICAL SUM-IN TO CARRY-OUT PROPAGATION DELAY TIME vs LOAD CAPACITANCE

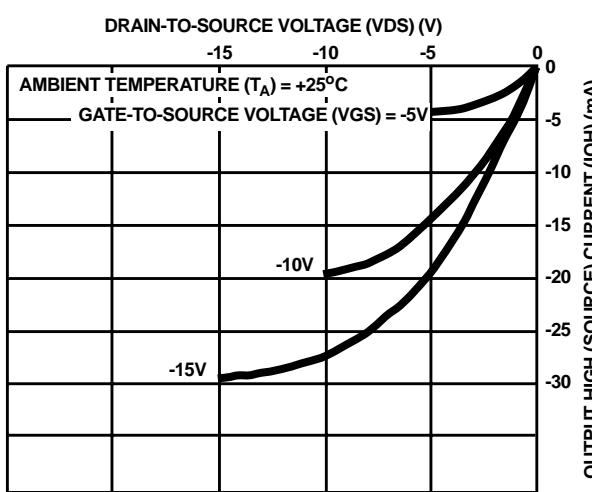


FIGURE 6. TYPICAL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

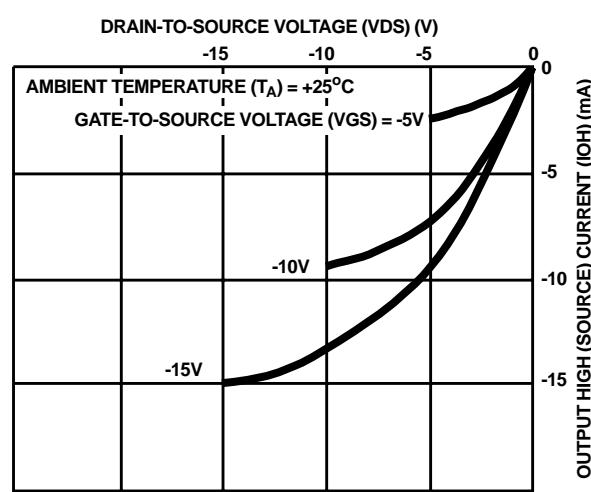


FIGURE 7. MINIMUM OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

CD4008BMS

Typical Performance Characteristics (Continued)

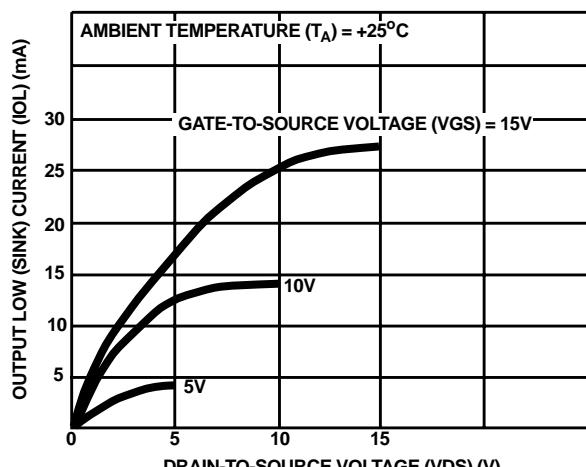


FIGURE 8. TYPICAL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

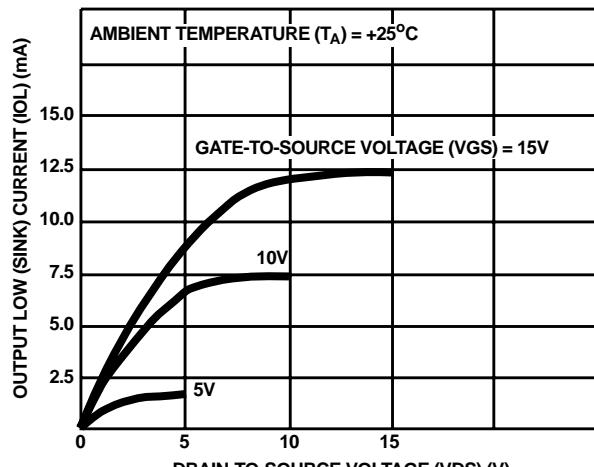


FIGURE 9. MINIMUM OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

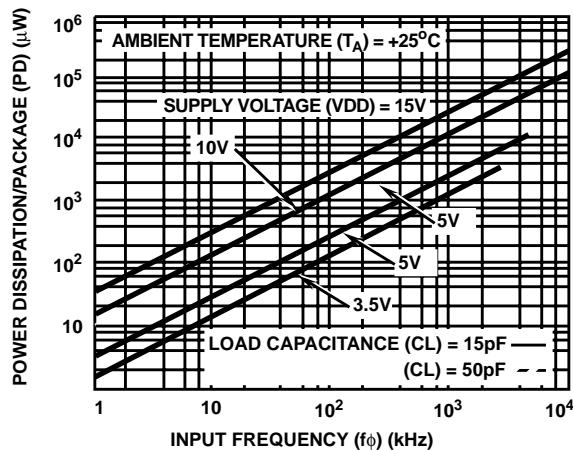
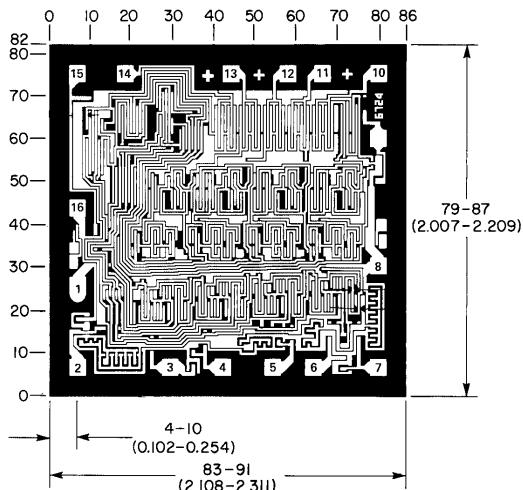


FIGURE 10. TYPICAL DISSIPATION CHARACTERISTICS

Chip Dimensions and Pad Layouts



Dimensions in parentheses are in millimeters
and are derived from the basic inch dimensions
as indicated. Grid graduations are in mils (10^{-3} inch)

METALLIZATION: Thickness: $11\text{k}\text{\AA} - 14\text{k}\text{\AA}$, AL.

PASSIVATION: $10.4\text{k}\text{\AA} - 15.6\text{k}\text{\AA}$, Silane

BOND PADS: 0.004 inches X 0.004 inches MIN

DIE THICKNESS: 0.0198 inches - 0.0218 inches